

PI49FCT3807

3.3V Fast CMOS Clock Driver

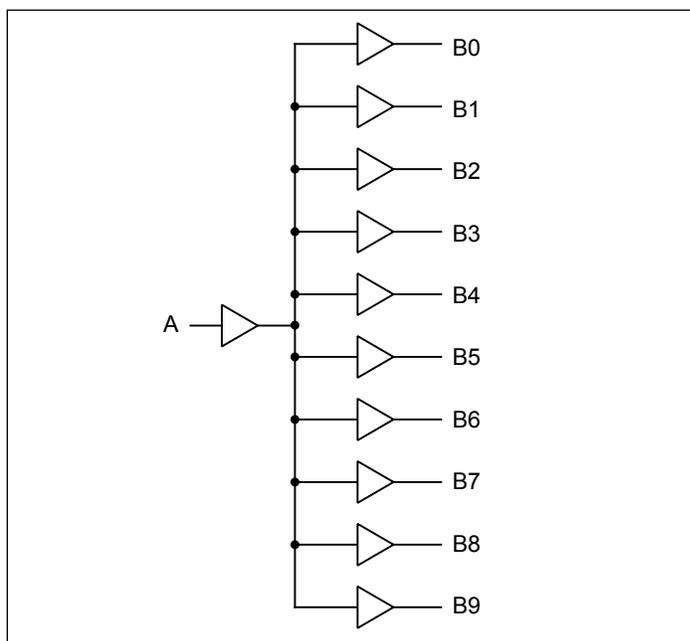
Features

- 3.3V version of PI49FCT807
- Ultra low skew: 0.35ns
- Low Input Capacitance
- Minimum duty cycle distortion
- 1:10 fanout
- High speed: 3.5ns propagation
- TTL input and CMOS output compatible
 - $V_{OH} = 3.3V$ (typical)
 - $V_{OL} = 0.3V$ (typical)
- Industrial Temperature: $-40^{\circ}C$ to $+85^{\circ}C$
- $3.3V \pm 10\%$ operation
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](#) or your local Diodes representative.
<https://www.diodes.com/quality/product-definitions/>
- Packaging (Pb-free & Green):
 - 20-pin 150-mil wide QSOP (Q)
 - 20-pin 209-mil wide SSOP (H)

Description

PI49FCT3807 is a 3.3V 1-to-10 clock driver. This low skew clock driver features one input and ten outputs fanout. The large fanout from a single input line reduced loading on input clock. TTL level outputs reduce noise levels on the part. Typical applications are clock and signal distribution.

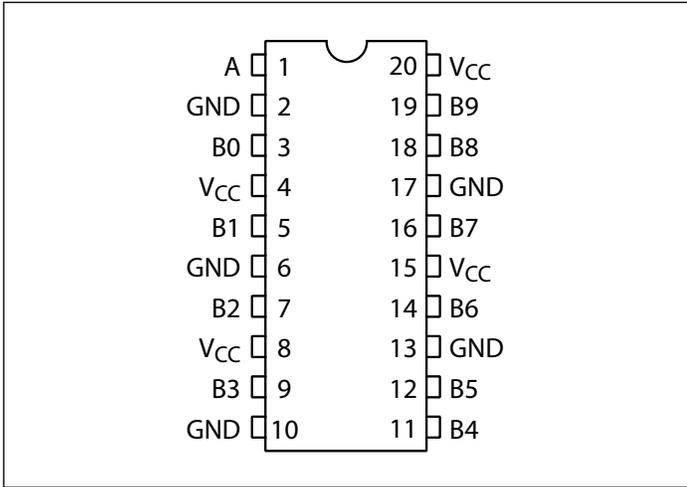
Block Diagram



Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Pin Configuration



Pin Description

| Pin # | Pin Name | Type | Description |
|------------------|-----------------|--------|---------------|
| 1 | A | I | Input Clock |
| 3 | B ₀ | O | Output Clock |
| 5 | B ₁ | O | Output Clock |
| 7 | B ₂ | O | Output Clock |
| 9 | B ₃ | O | Output Clock |
| 11 | B ₄ | O | Output Clock |
| 12 | B ₅ | O | Output Clock |
| 14 | B ₆ | O | Output Clock |
| 16 | B ₇ | O | Output Clock |
| 18 | B ₈ | O | Output Clock |
| 19 | B ₉ | O | Output Clock |
| 2, 6, 10, 13, 17 | GND | Ground | Ground Supply |
| 4, 8, 15, 20 | V _{CC} | Power | Power Supply |

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

| | |
|---|-----------------|
| Storage Temperature | -65°C to +150°C |
| Ambient Temperature with Power Applied | -40°C to +85°C |
| Supply Voltage to Ground Potential (Inputs & V _{CC} Only)..... | -0.5V to +7.0V |
| Supply Voltage to Ground Potential (Outputs & D/O Only) .. | -0.5V to +7.0V |
| DC Input Voltage | -0.5V to +7.0V |
| DC Output Current..... | 120mA |
| Power Dissipation | 0.5W |
| Latchup | 200mA |
| ESD Protection (Input) | 2000V min (HBM) |
| Junction Temperature..... | 125 °C max |

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

DC Electrical Characteristics (TA = -40°C to +85°C V_{CC} = 3.3V ±0.3V)

| Symbol | Parameter | Test Condition ⁽¹⁾ | Min. | Typ. | Max. | Units |
|-----------------|--|--|---|------------------------------|-------------------|-------|
| V _{OH} | Output High Voltage | V _{CC} = Min., V _{IN} = V _{IL} or V _{IH} | I _{OH} = -0.1mA I _{OH} = -8mA | V _{CC} - 0.2 2.4 | - 3.0 | V |
| V _{OL} | Output Low Voltage | V _{CC} = Min., V _{IN} = V _{IL} or V _{IH} | I _{OH} = 0.1mA I _{OH} = 16mA I _{OH} = 24mA | - 0.2 0.3 | 0.2 0.4 0.5 | |
| V _{IH} | Input High Voltage | Guaranteed Logic HIGH Level (Input pins) | | 2.0 | 5.5 | |
| V _{IL} | Input Low Voltage | Guaranteed Logic LOW Level (Input pins) | | -0.5 | 0.8 | |
| I _{IH} | Input High Current | V _{CC} = Max. | V _{IN} = V _{CC} | | 1 | µA |
| I _{IL} | Input Low Current | V _{CC} = Max. | V _{IN} = GND | | -1 | |
| V _{IK} | Clamp Diode Voltage | V _{CC} = Min., I _{IN} = -18mA | | | -0.7 -1.2 | V |
| I _{OH} | Output HIGH Current ^(4,5) | V _{OUT} = 1.5V, V _{IN} = V _{IL} or V _{IH} , V _{CC} = 3.3V | | -35 | -60 | mA |
| I _{OL} | Output LOW Current ^(4,5) | V _{OUT} = 1.5V, V _{IN} = V _{IL} or V _{IH} , V _{CC} = 3.3V | | 50 | 90 | |
| I _{OS} | Short Circuit Current ^(4,5) | V _{CC} = Max., V _{OUT} = GND | | -60 | -135 | |
| V _H | Input Hysteresis | | | | 150 | mV |

Notes:

- For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
- Typical values are at V_{CC} = 3.3V, +25°C ambient and maximum loading.
- V_{OH} = V_{CC} - 0.6V at rated current.
- This parameter is determined by device characterization but is not production tested.
- Not more than one output should be shorted at one time. Duration of the test should not exceed one second.

Power Supply Characteristics

| Parameters | Description | Test Conditions ⁽¹⁾ | | Min. | Typ ⁽²⁾ | Max. | Units |
|-----------------|---|--|--|------|--------------------|------|------------------------------|
| | | | | | | | |
| I_{CC} | Quiescent Power Supply Current | $V_{CC} = \text{Max.}$ | $V_{IN} = \text{GND or } V_{CC}$ | — | 3 | 30 | μA |
| ΔI_{CC} | Supply Current per Inputs @ TTL HIGH | $V_{CC} = \text{Max.}$ | $V_{IN} = V_{CC} - 0.6\text{V}^{(3)}$ | — | 2.0 | 300 | |
| I_{CCD} | Supply Current per Input per MHz ⁽⁴⁾ | $V_{CC} = \text{Max.},$ Outputs Open Per Output Toggling 50% Duty Cycle | $V_{IN} = V_{CC}$ $V_{IN} = \text{GND}$ | — | | | mA/ MHz |

Notes:

- For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device.
- Typical values are at $V_{CC} = 3.3\text{V}$, $+25^\circ\text{C}$ ambient.
- Per TTL driven input ($V_{IN} = V_{CC} - 0.6\text{V}$); all other inputs at V_{CC} or GND.
- This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.
- Values for these conditions are examples of the I_C formula. These limits are guaranteed but not tested.

Capacitance ($T_A = 25^\circ\text{C}$, $f = 1\text{ MHz}$)

| Parameters ⁽¹⁾ | Description | Test Conditions | Typ | Max. | Units |
|---------------------------|--------------------|-----------------------|-----|------|-------------|
| C_{IN} | Input Capacitance | $V_{IN} = 0\text{V}$ | 4.5 | 6.0 | pF |
| C_{OUT} | Output Capacitance | $V_{OUT} = 0\text{V}$ | 5.5 | 8.0 | |

Notes:

- This parameter is determined by device characterization but is not production tested.

Maximum Switching Characteristics (Over operating range)

| Symbol | Description | Test Conditions | 3807 | | 3087A | | 3087B | | 3807C | | Units |
|------------------------|---|--|------|------|-------|------|-------|------|-------|------|-------|
| | | | Com. | | Com. | | Com. | | Com. | | |
| | | | Min. | Max. | Min. | Max. | Min. | Max. | Min. | Max. | |
| t_{PLH} t_{PHL} | Propagation Delay A to B_N | $C_L = 15\text{pF}$ $R_L = 500\Omega$ | 1.5 | 4.5 | 1.5 | 4.0 | 1.5 | 3.8 | 1.5 | 3.5 | ns |
| $t_{SK(O)}$ | Skew between two outputs of same package ⁽³⁾ | | | 0.5 | | 0.5 | | 0.5 | | 0.5 | |
| $t_{SK(P)}$ | Skew between opposite transitions of the same output ($t_{PHL} - t_{PLH}$) ⁽³⁾ | | | 0.5 | | 0.5 | | 0.35 | | 0.35 | |
| t_{DC} | Duty Cycle | | | | | | | | | | |
| F_{IN} | Skew between outputs of different packages at the same power supply, temp. and speed grade ⁽³⁾ | | | 1.0 | | 1.0 | | 0.75 | | 0.75 | |

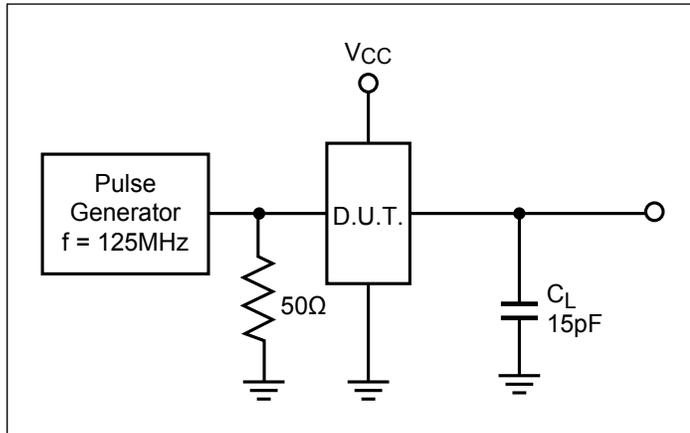
Notes:

- Other loading condition is described on page 4, "Test Circuits for All Outputs."
- These parameters are guaranteed by design.
- Minimum propagation delay of 1.5ns is guaranteed by design.

Phase Jitter Measurement Data

| Frequency Band | Input | Output | Additive Jitter | Unit |
|----------------|-------|--------|-----------------|-------------------|
| 12kHz-10MHz | 342 | 483 | 341 | fs _{RMS} |
| 12kHz-20MHz | 493 | 642 | 411 | fs _{RMS} |

Tests Circuits for All Outputs

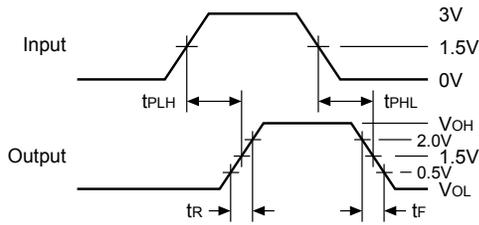


Switch Position

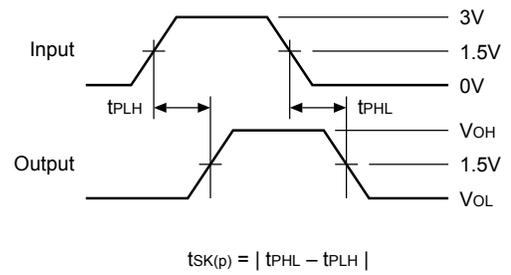
| Test | Switch |
|-----------------------------|--------|
| Disable LOW Enable LOW | 6V |
| Disable HIGH Enable HIGH | GND |
| All Other Inputs | Open |

Switching Waveforms

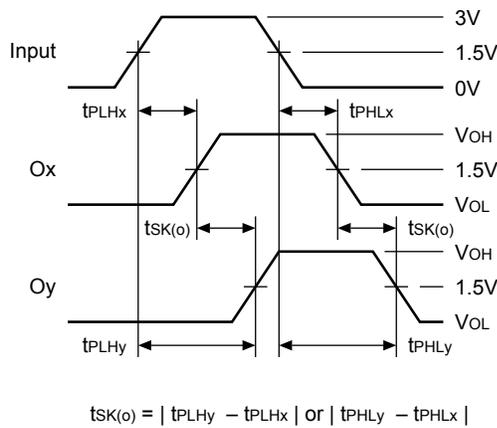
Propagation Delay



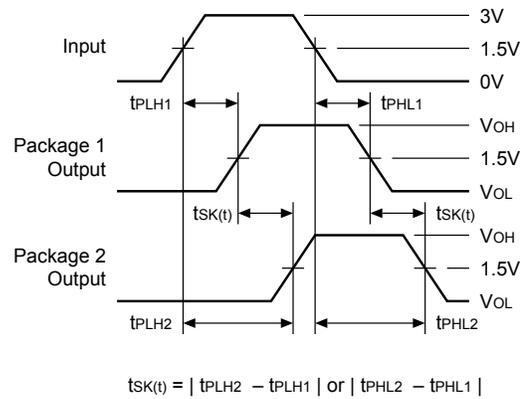
Pulse Skew – $t_{sk(p)}$



Output Skew – $t_{sk(o)}$



Package Skew – $t_{sk(t)}$



PI49FCT3807

Part Marking

H Package



B: Speed Code
YY: Year
WW: Workweek
1st X: Assembly Code
2nd X: Fab Code

Q Package



YY: Year
WW: Workweek
1st X: Assembly Code
2nd X: Fab Code



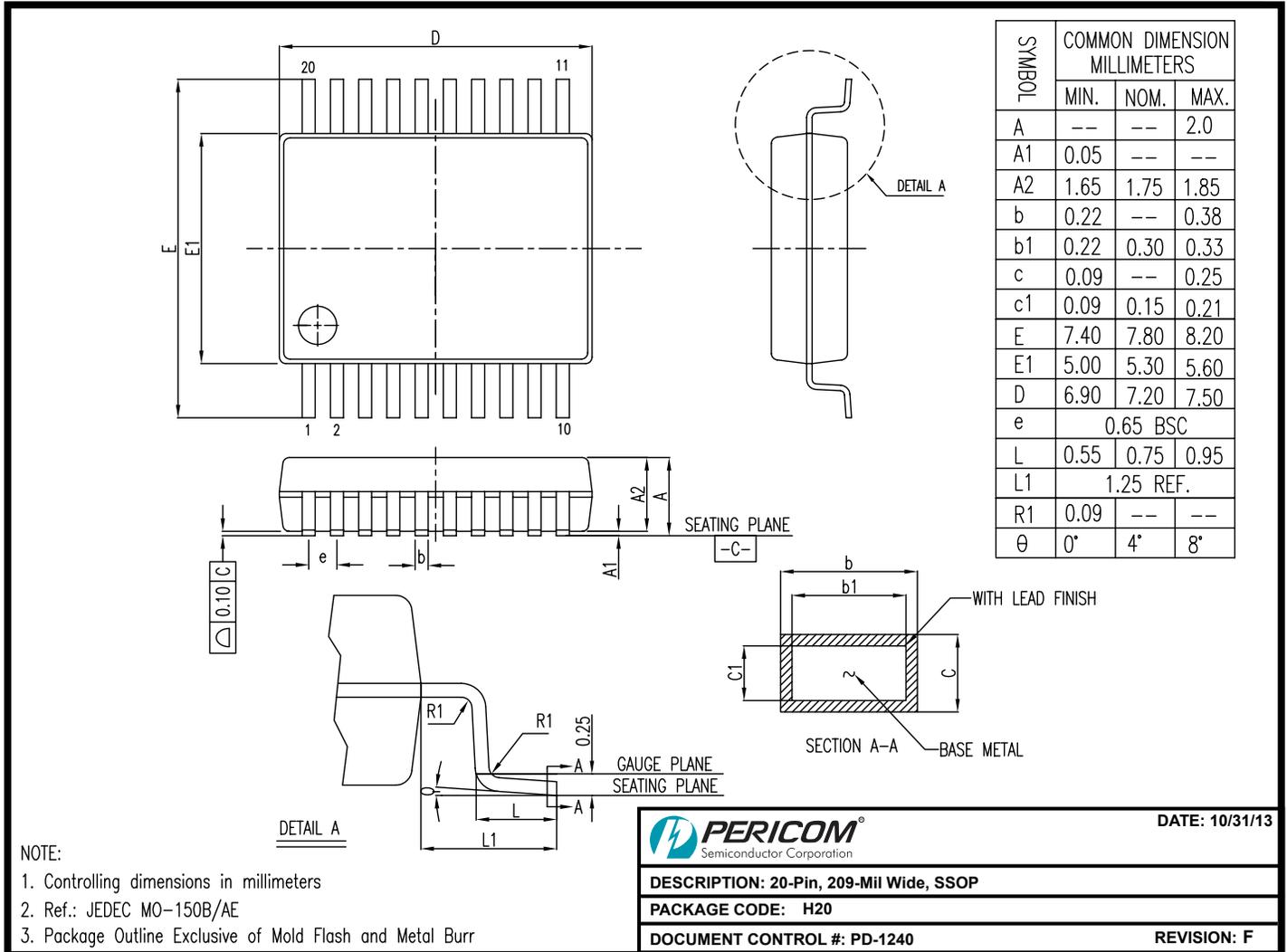
B: Speed Code
YY: Year
WW: Workweek
1st X: Assembly Code
2nd X: Fab Code



C: Speed Code
YY: Year
WW: Workweek
1st X: Assembly Code
2nd X: Fab Code

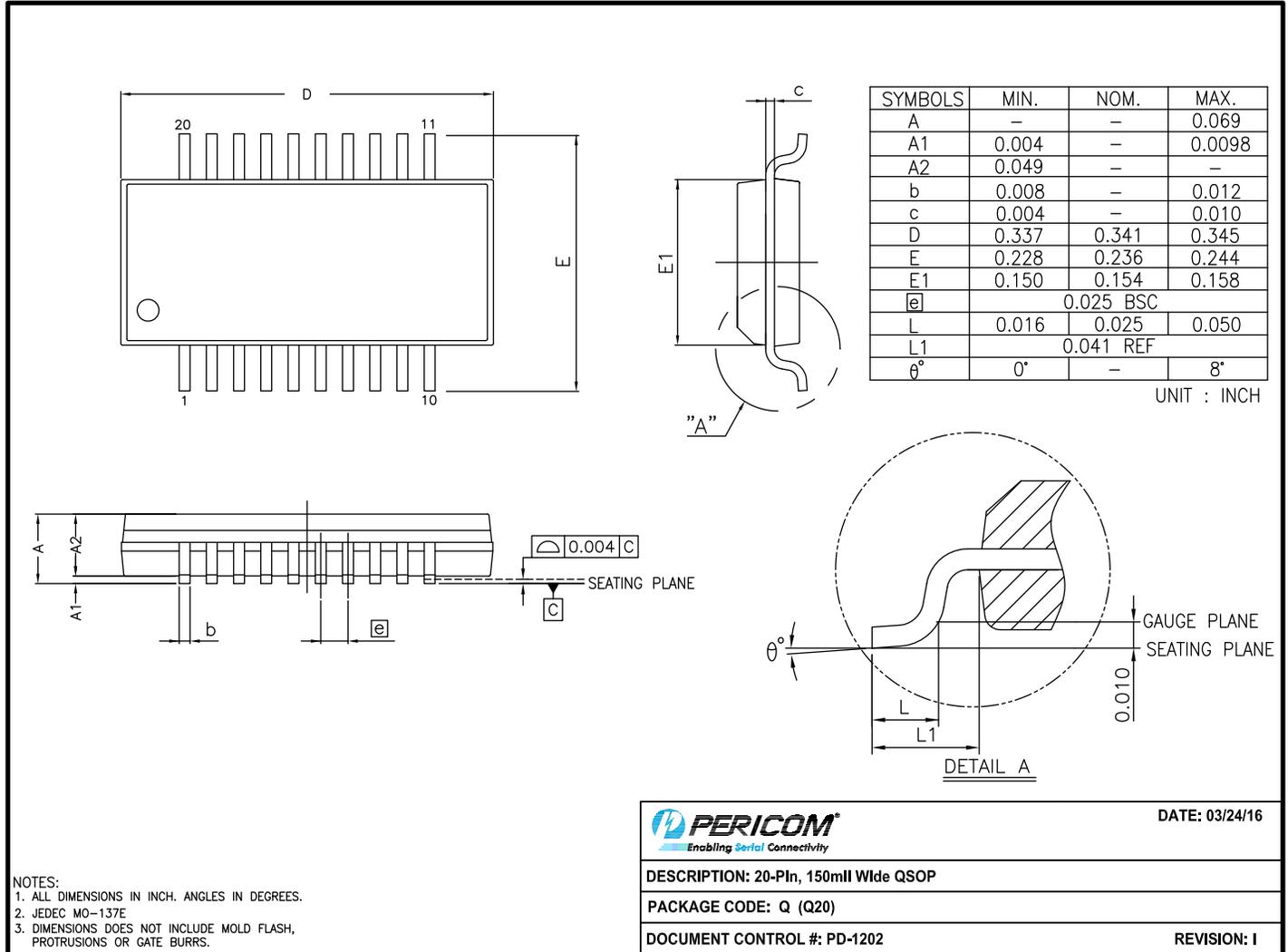
PI49FCT3807

Packaging Mechanical: 20-SSOP (H)



13-0214

Packaging Mechanical: 20-QSOP (Q)



16-0057

For latest package info.

please check: <http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/>

Ordering Information

| Ordering Code | Package Code | Speed Grade | Package Description |
|-----------------|--------------|-------------|---------------------|
| PI49FCT3807BQEX | Q | B | 20-pin 150-mil QSOP |
| PI49FCT3807CQEX | Q | C | 20-pin 150-mil QSOP |
| PI49FCT3807DHEX | H | D | 20-pin 209-mil SSOP |
| PI49FCT3807DQEX | Q | D | 20-pin 150-mil QSOP |
| PI49FCT3807QEX | Q | Blank | 20-pin 150-mil QSOP |

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. E = Pb-free and Green
5. X suffix = Tape/Reel

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